



**Diode, Wechselrichter / Diode, Inverter**

**Höchstzulässige Werte / Maximum Rated Values**

Periodische Spitzensperrspannung Repetitive peak reverse voltage	$T_{vj} = 25^{\circ}\text{C}$	$V_{RRM}$	1700	V
Dauergleichstrom Continuous DC forward current		$I_F$	2400	A
Periodischer Spitzenstrom Repetitive peak forward current	$t_P = 1\text{ ms}$	$I_{FRM}$	4800	A
Grenzlastintegral $I^2t$ - value	$V_R = 0\text{ V}, t_P = 10\text{ ms}, T_{vj} = 125^{\circ}\text{C}$ $V_R = 0\text{ V}, t_P = 10\text{ ms}, T_{vj} = 150^{\circ}\text{C}$	$I^2t$	1400 1350	$\text{kA}^2\text{s}$ $\text{kA}^2\text{s}$
Spitzenverlustleistung Maximum power dissipation	$T_{vj} = 125^{\circ}\text{C}$	$P_{RQM}$	3600	kW
Mindesteinschaltdauer Minimum turn-on time		$t_{on\ min}$	10,0	$\mu\text{s}$

**Charakteristische Werte / Characteristic Values**

		min. typ. max.			
Durchlassspannung Forward voltage	$I_F = 2400\text{ A}, V_{GE} = 0\text{ V}$ $I_F = 2400\text{ A}, V_{GE} = 0\text{ V}$ $I_F = 2400\text{ A}, V_{GE} = 0\text{ V}$	$T_{vj} = 25^{\circ}\text{C}$ $T_{vj} = 125^{\circ}\text{C}$ $T_{vj} = 150^{\circ}\text{C}$	$V_F$	1,65 1,65 1,65	2,10 V V V
Rückstromspitze Peak reverse recovery current	$I_F = 2400\text{ A}, -di_F/dt = 13500\text{ A}/\mu\text{s} (T_{vj}=150^{\circ}\text{C})$ $V_R = 900\text{ V}$ $V_{GE} = -15\text{ V}$	$T_{vj} = 25^{\circ}\text{C}$ $T_{vj} = 125^{\circ}\text{C}$ $T_{vj} = 150^{\circ}\text{C}$	$I_{RM}$	2800 3200 3300	A A A
Sperrverzögerungsladung Recovered charge	$I_F = 2400\text{ A}, -di_F/dt = 13500\text{ A}/\mu\text{s} (T_{vj}=150^{\circ}\text{C})$ $V_R = 900\text{ V}$ $V_{GE} = -15\text{ V}$	$T_{vj} = 25^{\circ}\text{C}$ $T_{vj} = 125^{\circ}\text{C}$ $T_{vj} = 150^{\circ}\text{C}$	$Q_r$	665 1150 1300	$\mu\text{C}$ $\mu\text{C}$ $\mu\text{C}$
Abschaltenergie pro Puls Reverse recovery energy	$I_F = 2400\text{ A}, -di_F/dt = 13500\text{ A}/\mu\text{s} (T_{vj}=150^{\circ}\text{C})$ $V_R = 900\text{ V}$ $V_{GE} = -15\text{ V}$	$T_{vj} = 25^{\circ}\text{C}$ $T_{vj} = 125^{\circ}\text{C}$ $T_{vj} = 150^{\circ}\text{C}$	$E_{rec}$	470 840 950	mJ mJ mJ
Wärmewiderstand, Chip bis Gehäuse Thermal resistance, junction to case	pro Diode / per diode		$R_{thJC}$		10,6 K/kW
Wärmewiderstand, Gehäuse bis Kühlkörper Thermal resistance, case to heatsink	pro Diode / per diode $\lambda_{Paste} = 1\text{ W}/(\text{m}\cdot\text{K})$ / $\lambda_{grease} = 1\text{ W}/(\text{m}\cdot\text{K})$		$R_{thCH}$	11,0	K/kW
Temperatur im Schaltbetrieb Temperature under switching conditions			$T_{vj\ op}$	-40	150 $^{\circ}\text{C}$

prepared by: WB	date of publication: 2016-01-21
approved by: IB	revision: V3.1



**Modul / Module**

Isolations-Prüfspannung Isolation test voltage	RMS, f = 50 Hz, t = 1 min.	V <sub>ISOL</sub>	4,0		kV
Material Modulgrundplatte Material of module baseplate			AlSiC		
Kriechstrecke Creepage distance	Kontakt - Kühlkörper / terminal to heatsink Kontakt - Kontakt / terminal to terminal		32,2 32,2		mm
Luftstrecke Clearance	Kontakt - Kühlkörper / terminal to heatsink Kontakt - Kontakt / terminal to terminal		19,1 19,1		mm
Vergleichszahl der Kriechwegbildung Comperative tracking index		CTI	> 400		
			min.	typ.	max.
Modulstreuintuktivität Stray inductance module		L <sub>sCE</sub>		6,0	nH
Modulleitungswiderstand, Anschlüsse - Chip Module lead resistance, terminals - chip	T <sub>c</sub> = 25°C, pro Schalter / per switch	R <sub>CC+EE'</sub>		0,10	mΩ
Lagertemperatur Storage temperature		T <sub>stg</sub>	-40		150 °C
Anzugsdrehmoment f. Modulmontage Mounting torque for modul mounting	Schraube M6 - Montage gem. gültiger Applikationsschrift Screw M6 - Mounting according to valid application note	M	4,25		5,75 Nm
Anzugsdrehmoment f. elektr. Anschlüsse Terminal connection torque	Schraube M4 - Montage gem. gültiger Applikationsschrift Screw M4 - Mounting according to valid application note	M	1,8	-	2,1 Nm
	Schraube M8 - Montage gem. gültiger Applikationsschrift Screw M8 - Mounting according to valid application note		8,0	-	10 Nm
Gewicht Weight		G		1200	g

prepared by: WB	date of publication: 2016-01-21
approved by: IB	revision: V3.1